TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

# 2SA1312

## Audio Frequency Low Noise Amplifier Applications

Unit: mm

• High voltage: VCEO = -120 V

• Excellent hFE linearity: hFE (IC = -0.1 mA)/ hFE (IC = -2 mA) h= 0.95 (typ.)

• High hfe: hfe =  $200 \sim 700$ 

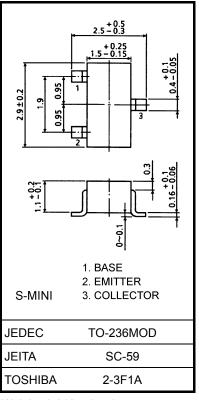
Low noise: NF (2) = 0.2dB (typ.), 3dB (max) at f = 1 kHz

• Complementary to 2SC3324

• Small package

## **Absolute Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	-120	V
Collector-emitter voltage	V <sub>CEO</sub>	-120	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	IC	-100	mA
Base current	ΙΒ	-20	mA
Collector power dissipation	PC	150	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C



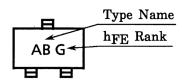
Weight: 0.012 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high

temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

# Marking





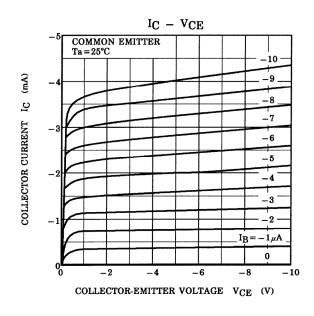
# **Electrical Characteristics (Ta = 25°C)**

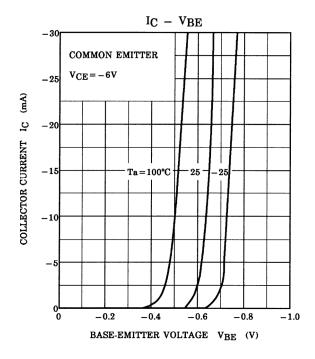
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit	
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -120 \text{ V}, I_E = 0$	_	_	-0.1	μА	
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -5 \text{ V}, I_C = 0$	_	_	-0.1	μΑ	
DC current gain	h <sub>FE</sub> (Note)	V <sub>CE</sub> = -6 V, I <sub>C</sub> = -2 mA	200	_	700		
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	$I_C = -10 \text{ mA}, I_B = -1 \text{ mA}$	_	_	-0.3	V	
Transition frequency	f <sub>T</sub>	$V_{CE} = -6 \text{ V}, I_{C} = -1 \text{ mA}$	_	100	_	MHz	
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = -10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$	_	4	_	pF	
Noise figure ————	NF (1)	$V_{CE}$ = -6 V, $I_{C}$ = -0.1 mA, f = 100 Hz, Rg = 10 k $\Omega$	_	0.5	6	dB	
	NF (2)	$V_{CE}$ = -6 V, $I_{C}$ = -0.1 mA, $f$ = 1 kHz, Rg = 10 k $\Omega$	_	0.2	3	uБ	

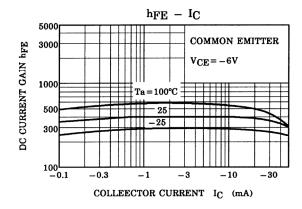
Note: hFE classification GR (G): 200~400, BL (L): 350~700

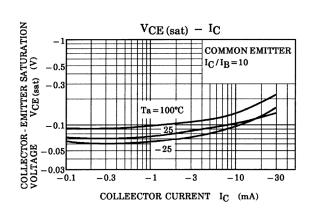
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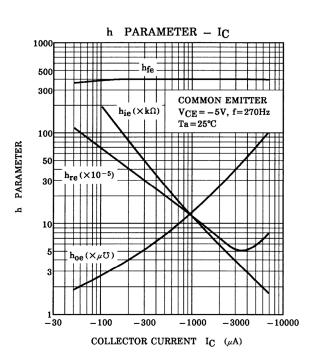
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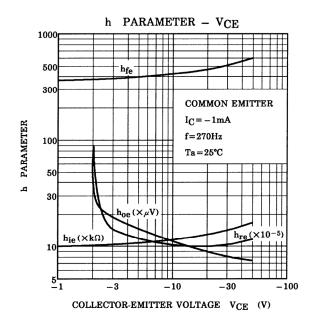


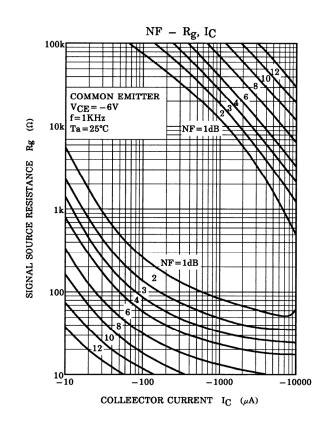


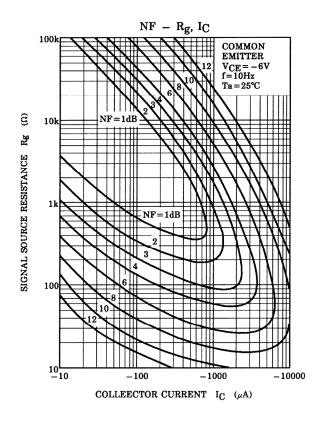


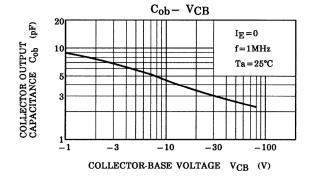


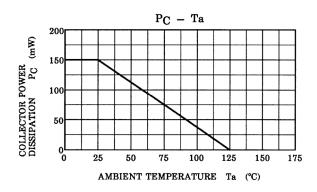
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20070701-EN GENERAL

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